NSN 5961-01-066-5563

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-066-5563 **Inclosure Material:** Glass **Overall Length:** 0.615 inches **Terminal Length:** Between 0.420 inches and 0.455 inches **Overall Width:** Between 0.551 inches and 0.559 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Mounting hardware **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 10.0 peak positive gate voltage **Current Rating Per Characteristic:** 2.00 amperes forward current, total rms of standard range **Power Rating Per Characteristic:** 20.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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